ENSC 450: Assignment 2

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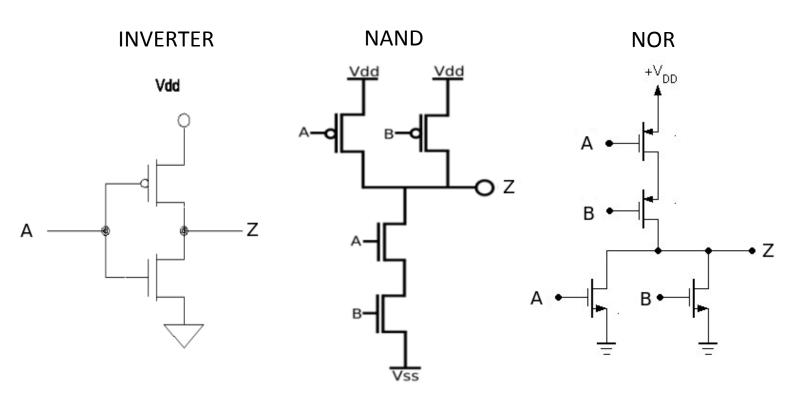
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<u>Outline</u>

- Scope of Presentation:
 - Perform CMOS logic cell analysis, using HSPICE circuit simulator
 - Determine the size of internal transistors to yield raise/fall Output Transition Time <100ps
 - Evaluate the setup and hold time of the Flip-Flop designed considering clock transition time of 100ps.
- Methodology Used
- Results
- Conclusion

Methodology (1)

Designed simple logic gates using HSPICE



Logic of AND gate

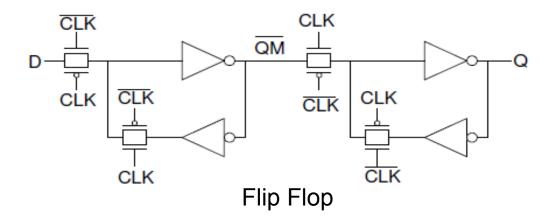
Logic of OR gate

Xnand a b d vdd gnd vdds gnds NAND Wn=Wm#
Xinv d z vdd gnd vdds gnds INV Wn=Wm#

Xnor a b d vdd gnd vdds gnds NOR Wn=Wm#
Xinv d z vdd gnd vdds gnds INV Wn=Wm#

Methodology (2)

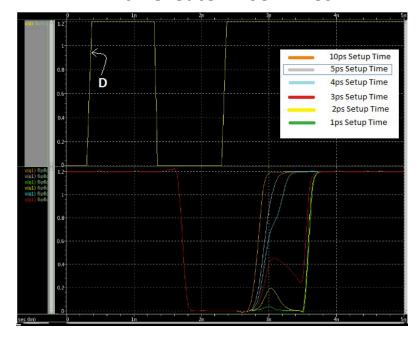
- Designed a Flip-Flop using logic gates from Methodology 1
- Varied size ratio between PMOS and NMOS transistors in order to decrease rise and fall times to below 100ps
- Determined the setup time of FF by continuously decreasing the time frame between input transition (D) and clock transition until output (Q) becomes distorted
- Pin pointed the hold time of FF by changing the input (D) soon after clock begins to rise, and viewing output to see if desired waveform is produced
- Reduced setup time until greater rise/fall transition times were observed



Results

Logic Operation	Number of Transistors
AND	6
NAND	4
NOR	4
OR	6
INVERTER	2

Setup Time Waveforms with Greater Rise Times

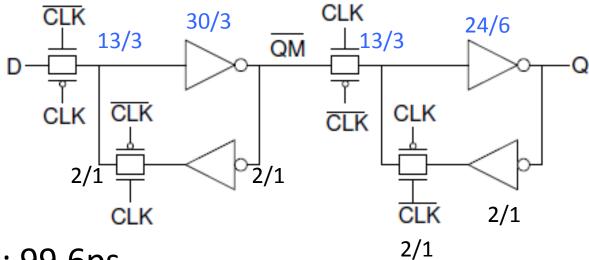


Final Results:



Conclusion

Width Ratios of PMOS/NMOS:



• Rise Time: 99.6ps

• Fall Time: 86.5ps

Set-up Time: 25ps

If <25ps, then rise time would increase >100ps

• Hold Time: 120ps

If <120ps, then output is distorted